

Device Modeling Report

COMPONENTS:

DIODE/ SCHOOTTKY RECTIFIER /STANDARD

PART NUMBER: ESL03B03-F

MANUFACTURER: NIEC

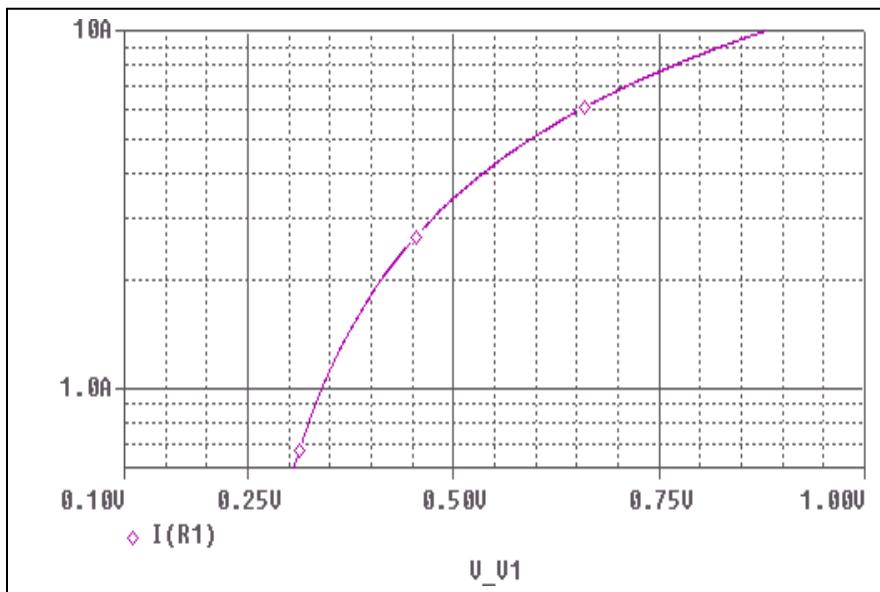


Bee Technologies Inc.

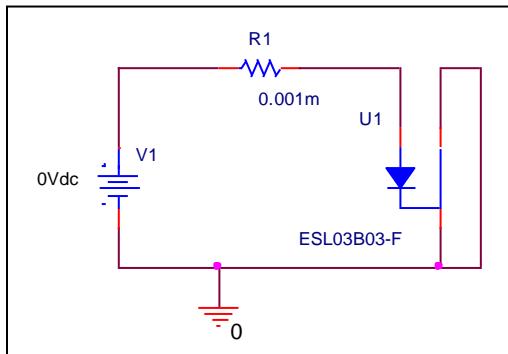
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

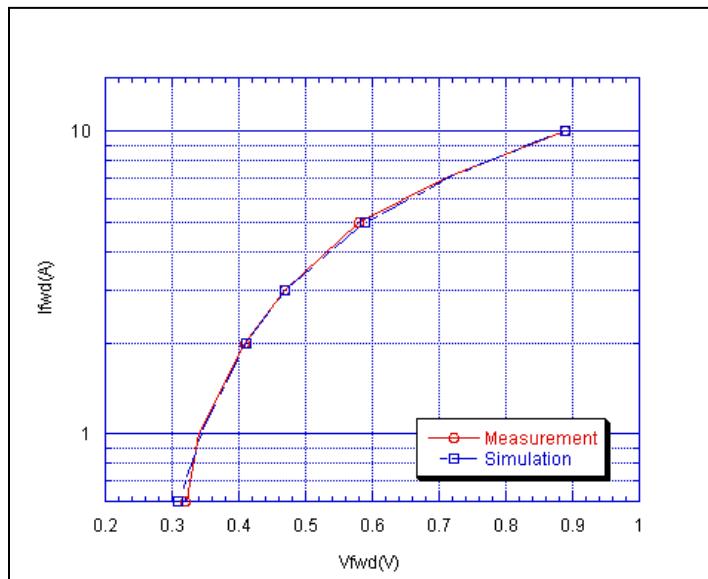


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

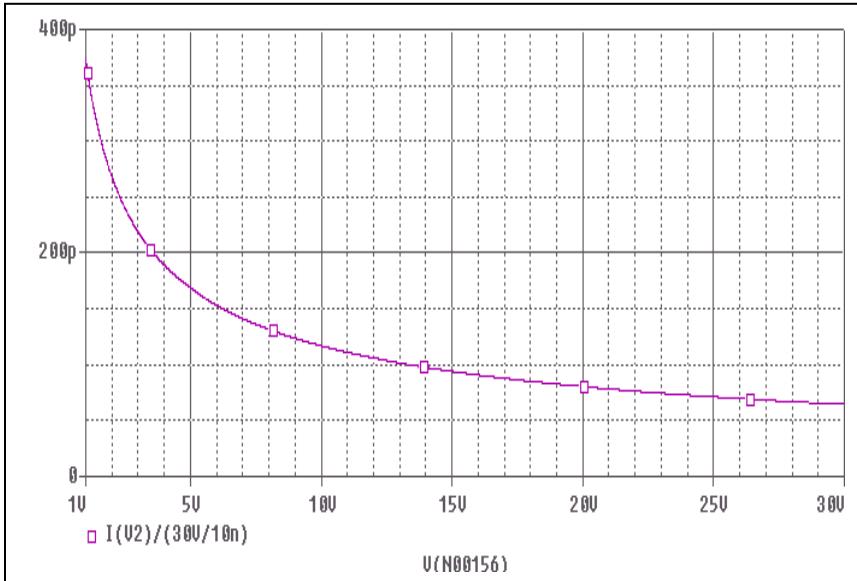


Simulation Result

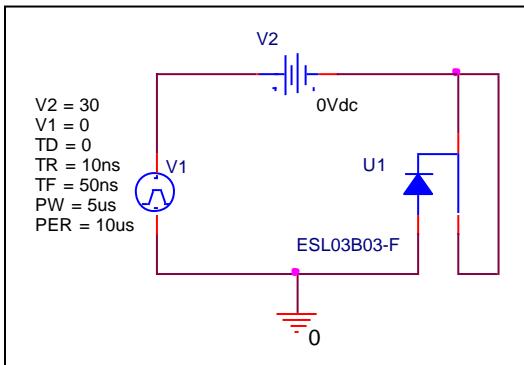
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
1	0.340	0.345	1.47
2	0.410	0.412	0.49
5	0.588	0.590	0.34
10	0.890	0.885	-0.56

Capacitance Characteristic

Circuit Simulation Result

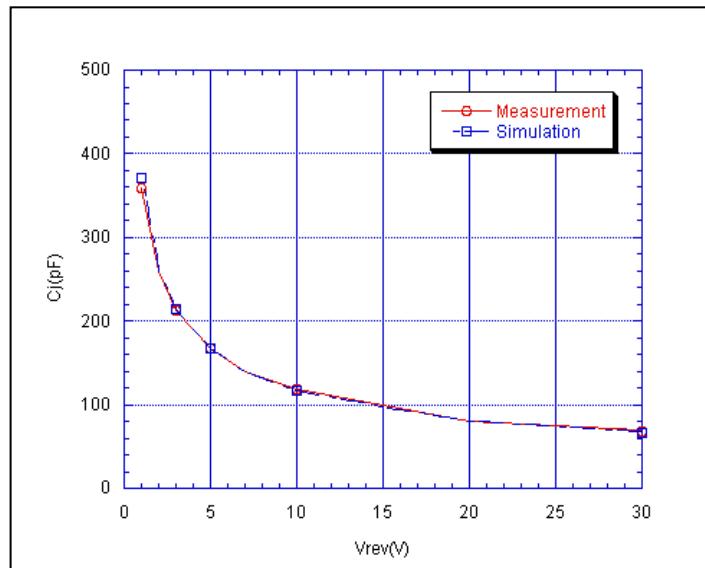


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

V_{rev} (V)	C_j (pF) Measurement	C_j (pF) Simulation	%Error
1	359.000	372.000	3.62
2	259.000	261.000	0.77
5	167.000	168.000	0.60
10	118.000	117.000	-0.85
20	80.400	80.300	-0.12
30	68.000	67.000	-1.47